



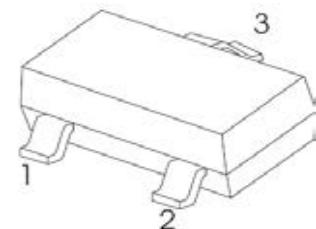
迈拓电子
MAITUO ELECTRONIC

BAT64, BAT64-04, BAT64-05, BAT64-06

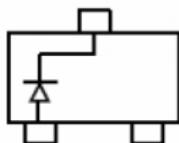
SCHOTTKY BARRIER DIODE

FEATURES

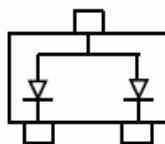
- For low-loss, fast-recovery, meter protection, bias isolation and clamping applications
- Integrated diffused guard ring
- Low forward voltage



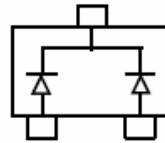
SOT-23



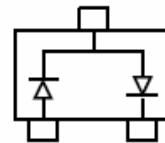
BAT64 MARKING: 67S



BAT64-06 MARKING: 66S



BAT64-05 MARKING: 65S



BAT64-04 MARKING: 64S

Maximum Ratings @ $T_a=25^\circ\text{C}$

Parameter	Symbol	Limits		Unit
Peak reverse voltage	V_{RM}		40	V
DC reverse	V_R			
Non-repetitive Peak forward surge current @ $t=8.3\text{ms}$	I_{FSM}	0.8		A
Forward current	I_F	0.25		A
Power Dissipation	P_D	250		mW
Thermal Resistance Junction-to-Ambient	$R_{\Theta JA}$	400		$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_j	-40 ~ +125		$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150		$^\circ\text{C}$

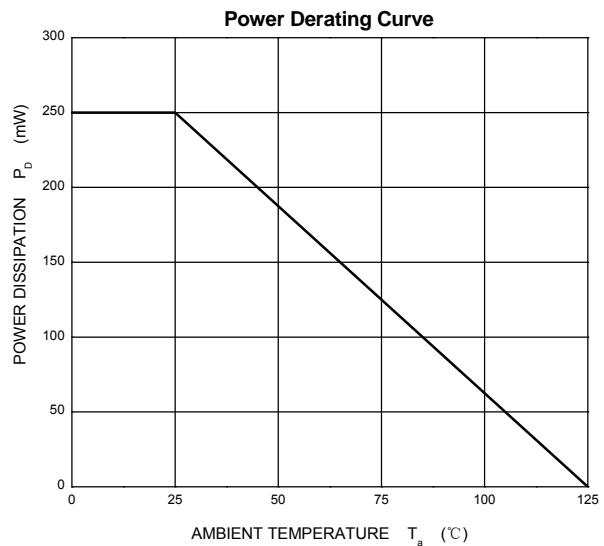
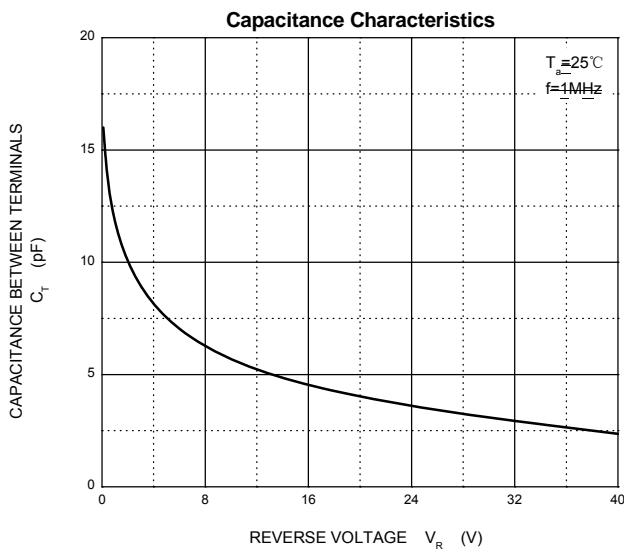
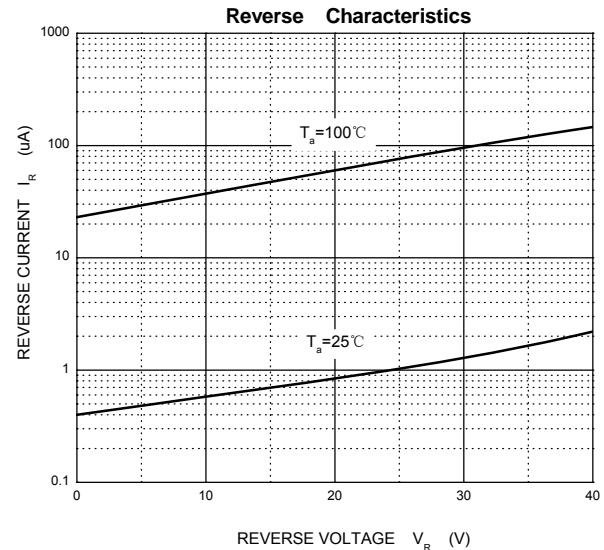
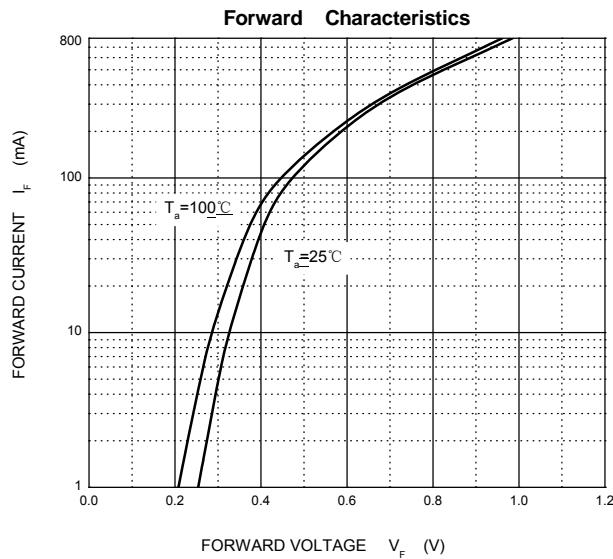
Electrical Ratings @ $T_a=25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Reverse breakdown voltage	V_R	40			V	$I_R=10\mu\text{A}$
Forward voltage	V_F			350 430 520 750	mV	$I_F=1\text{mA}$ $I_F=10\text{mA}$ $I_F=30\text{mA}$ $I_F=100\text{mA}$
Reverse current	I_R			2	μA	$V_R=25\text{V}$
Capacitance between terminals	C_T		6		pF	$V_R=1\text{V}, f=1\text{MHz}$



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Typical Characteristics



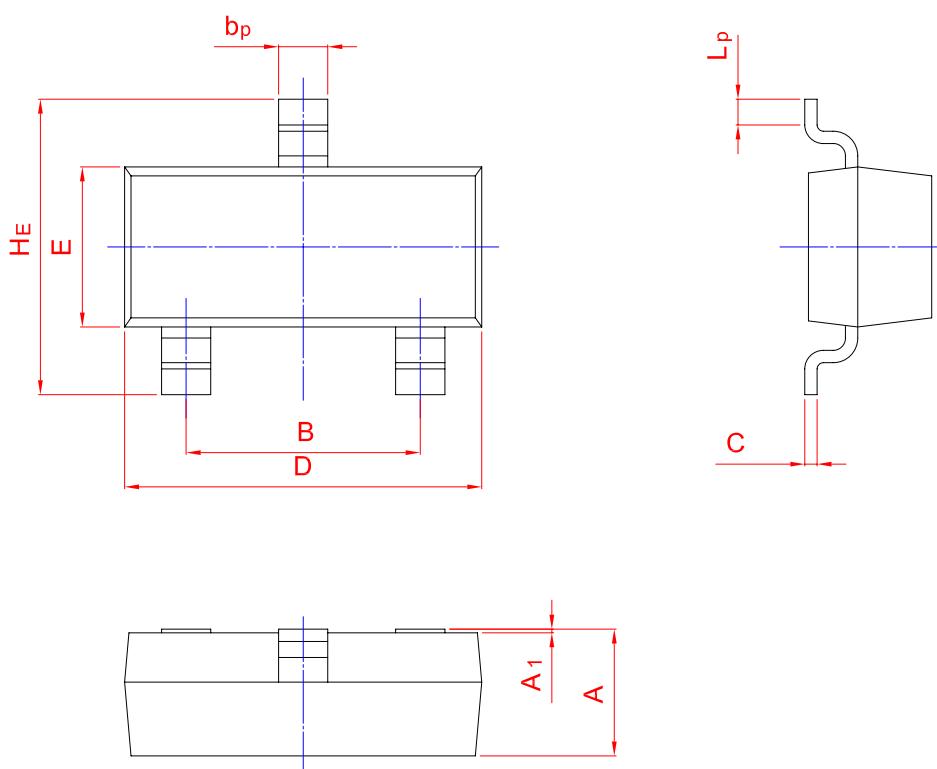


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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b_p	C	D	E	H_E	A_1	L_p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20